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APPENDIX TO SUPPLEMENTAL AMENDMENT OF May 20, 2002

Version of Claims with Markings to Show Changes Made

AMENDMENTS TO THE CLAIMS:

Please amend claims 14, 15, 21, and 22 as follows:

14. (Amended) The semiconductor device according to claim 13, wherein a thickness of the [Ta] TaN film is 20 nm or more.

15. (Amended) The semiconductor device according to claim 13, wherein a thickness of the [Ta] TaN film is 40 nm or more.

21. (Amended) The semiconductor device according to claim 20, wherein a thickness of the [Ta] TaN film is 20 nm or more.

22. (Amended) The semiconductor device according to claim 20, wherein a thickness of the [Ta] TaN film is 40 nm or more.--

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